

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- SMPS for battery charger

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The STX13004G and STX13004G-AP are supplied using halogen-free molding compound.

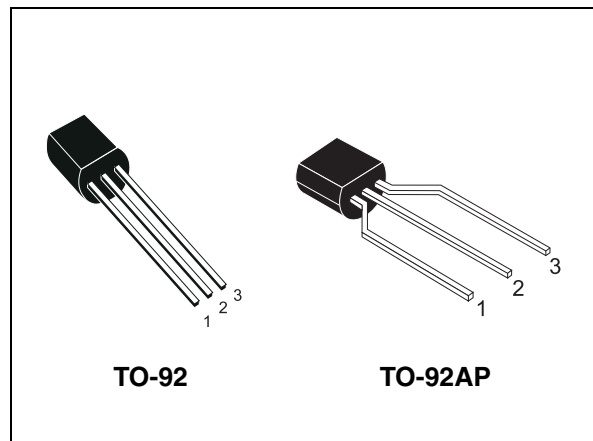


Figure 1. Internal schematic diagram

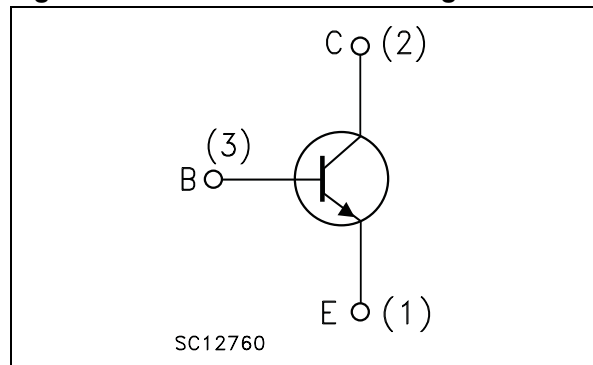


Table 1. Device summary

Order codes	Marking	Package	Packaging
STX13004	X13004	TO-92	Bulk
STX13004G	X13004G	TO-92	Bulk
STX13004-AP	X13004	TO-92AP	Ammopack
STX13004G-AP	X13004G	TO-92AP	Ammopack

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1 Electrical ratings

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Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Collector-base voltage ($I_C = 0, I_B = 1\text{ A}, t_P < 10\text{ ms}$)	$V_{(BR)EBO}$	V
I_C	Collector current	2	A
I_{CM}	Collector peak current ($t_P < 5\text{ ms}$)	4	A
I_B	Base current	1	A
I_{BM}	Base peak current ($t_P < 5\text{ ms}$)	2	A
P_{TOT}	Total dissipation at $T_C = 25\text{ °C}$	2.5	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case max	50	°C/W

2 Electrical characteristics

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($T_{case} = 25\text{ °C}$; unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{BE} = 0$)	$V_{CE} = 700\text{ V}$			1	mA
		$V_{CE} = 700\text{ V}$ $T_C = 125\text{ °C}$			5	mA
I_{CEO}	Collector cut-off current ($I_B = 0$)	$V_{CE} = 400\text{ V}$			1	mA
$V_{(BR)EBO}$	Emitter-base breakdown voltage ($I_C = 0$)	$I_E = 10\text{ mA}$	9		18	V
$V_{CEQ(sus)}^{(1)}$	Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = 10\text{ mA}$	400			V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = 1\text{ A}$ $I_B = 200\text{ mA}$			0.5	V
		$I_C = 2\text{ A}$ $I_B = 500\text{ mA}$			1	V
$V_{BE(sat)}^{(1)}$	Base-emitter saturation voltage	$I_C = 1\text{ A}$ $I_B = 200\text{ mA}$			1.2	V
		$I_C = 2\text{ A}$ $I_B = 500\text{ mA}$			1.6	V
h_{FE}	DC current gain	$I_C = 0.5\text{ mA}$ $V_{CE} = 2\text{ V}$	15	35		
		$I_C = 425\text{ mA}$ $V_{CE} = 2\text{ V}$	24			
		$I_C = 1\text{ A}$ $V_{CE} = 5\text{ V}$	10		30	
		$I_C = 2\text{ A}$ $V_{CE} = 5\text{ V}$	6		16	
t_s t_f	Resistive load Storage time	$I_C = 2\text{ A}$ $t_p = 30\text{ }\mu\text{s}$ $I_{B(on)} = -I_{B(off)} = 400\text{ mA}$ $V_{CC} = 125\text{ V}$ $V_{BB(off)} = -5\text{ V}$ (see Figure 12)		1.1		μs
	Fall time			300		ns
t_s t_f	Inductive load Storage time	$I_C = 1\text{ A}$ $V_{clamp} = 300\text{ V}$ $I_{B(on)} = 200\text{ mA}$ $V_{BB(off)} = -5\text{ V}$ $L = 50\text{ mH}$ $R_{BB(off)} = 0$ (see Figure 13)		0.6		μs
	Fall time			80		ns

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

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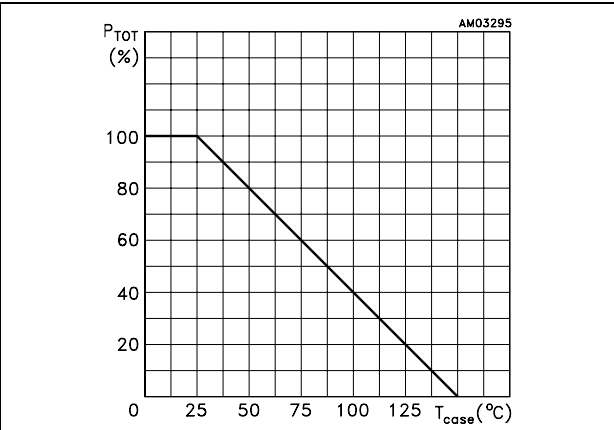
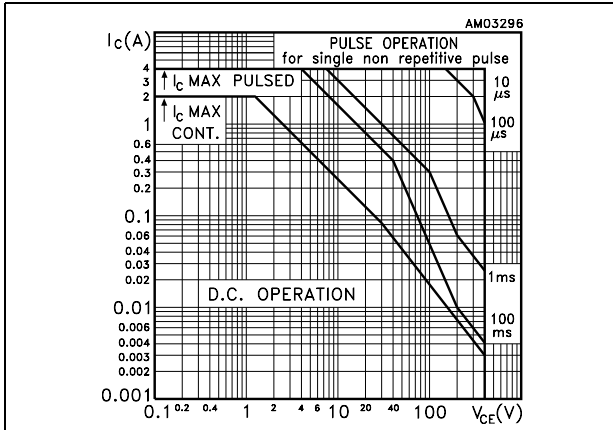


Figure 4. DC current gain @ $V_{CE} = 2\text{ V}$

Figure 5. DC current gain @ $V_{CE} = 5\text{ V}$

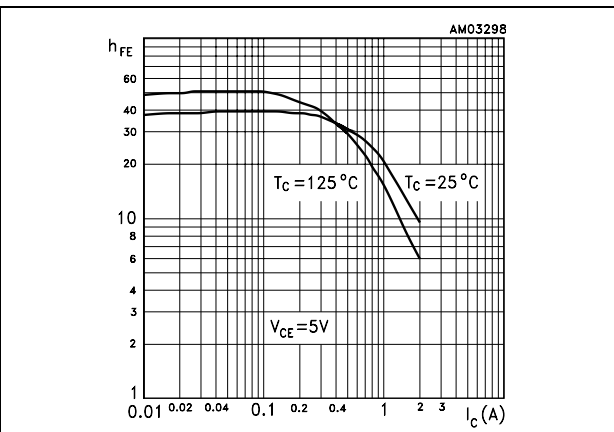
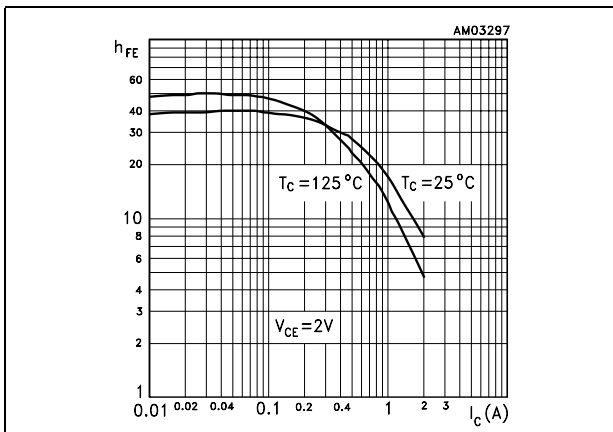


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage

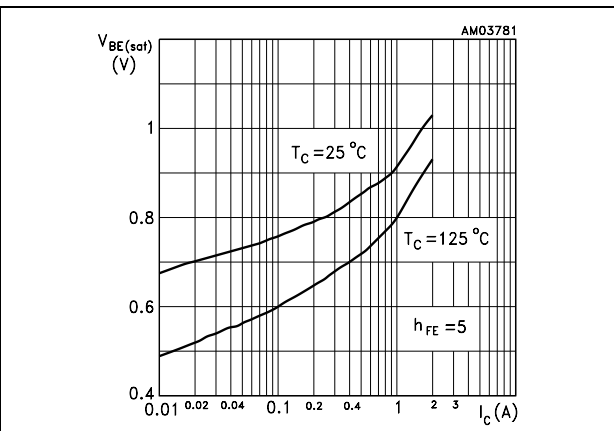
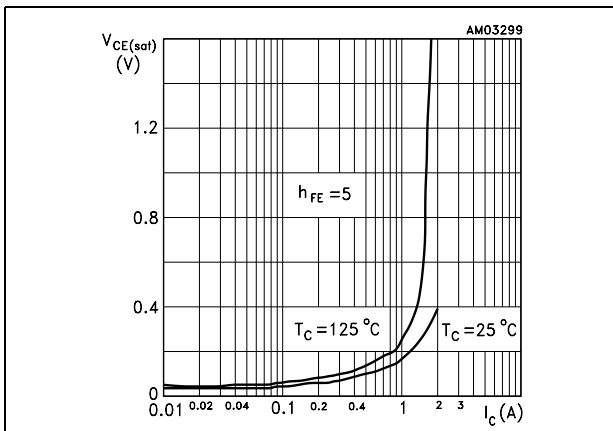


Figure 8. Output characteristics

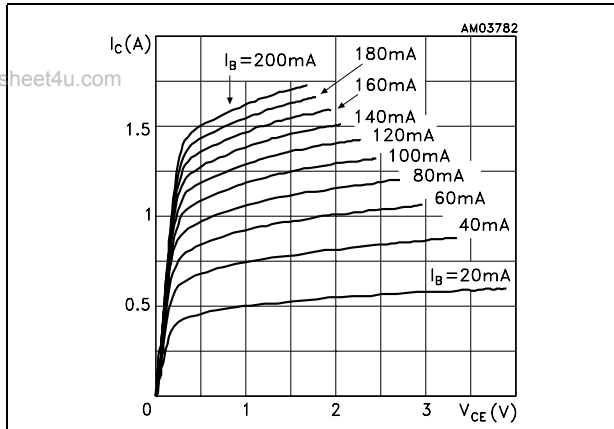


Figure 9. Reverse biased SOA

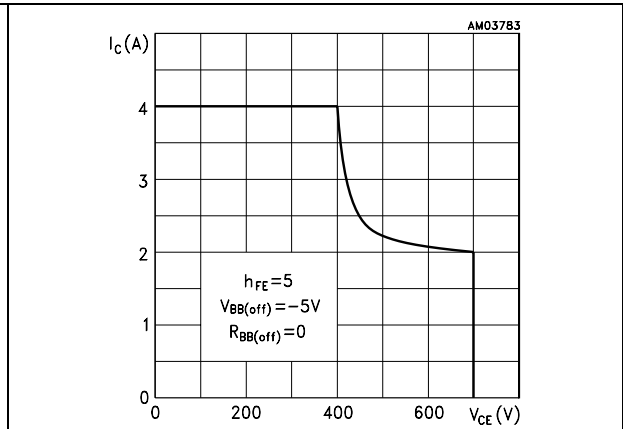


Figure 10. Resistive load switching times

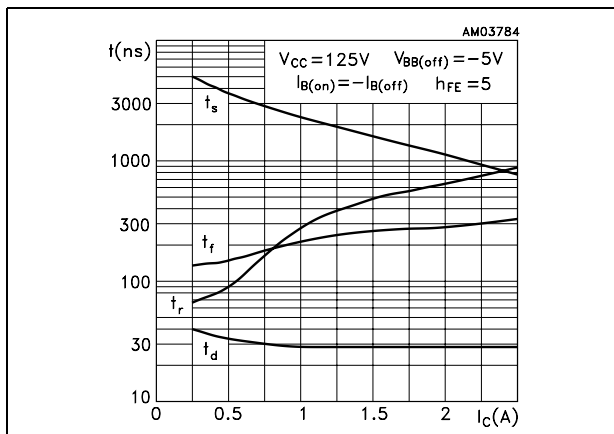
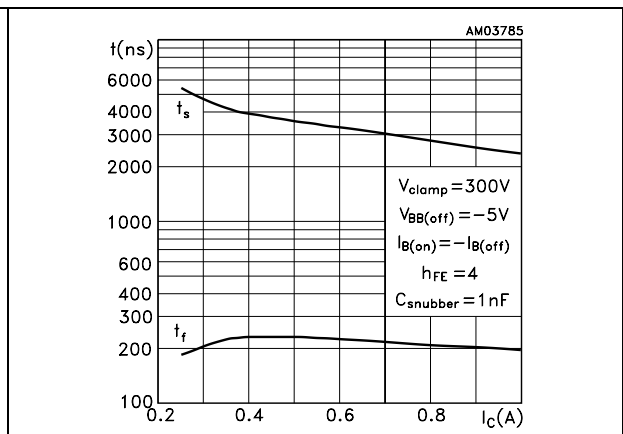


Figure 11. Inductive load switching times



2.2 Test circuits

Figure 12. Resistive load switching test circuit

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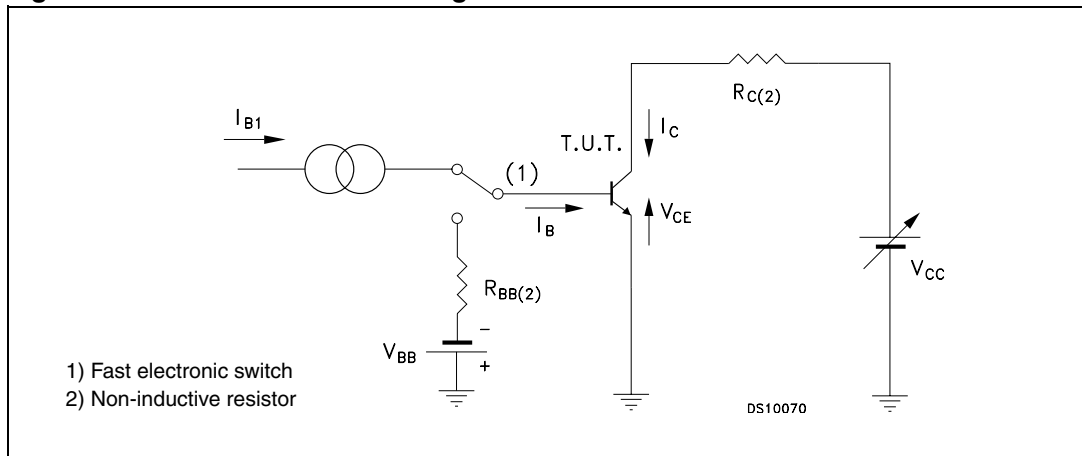
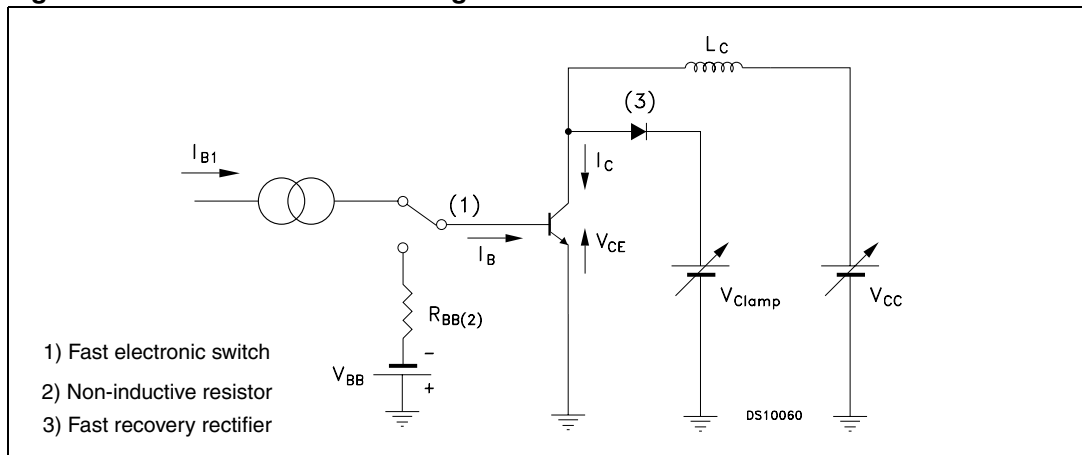


Figure 13. Inductive load switching test circuit



3 Package mechanical data

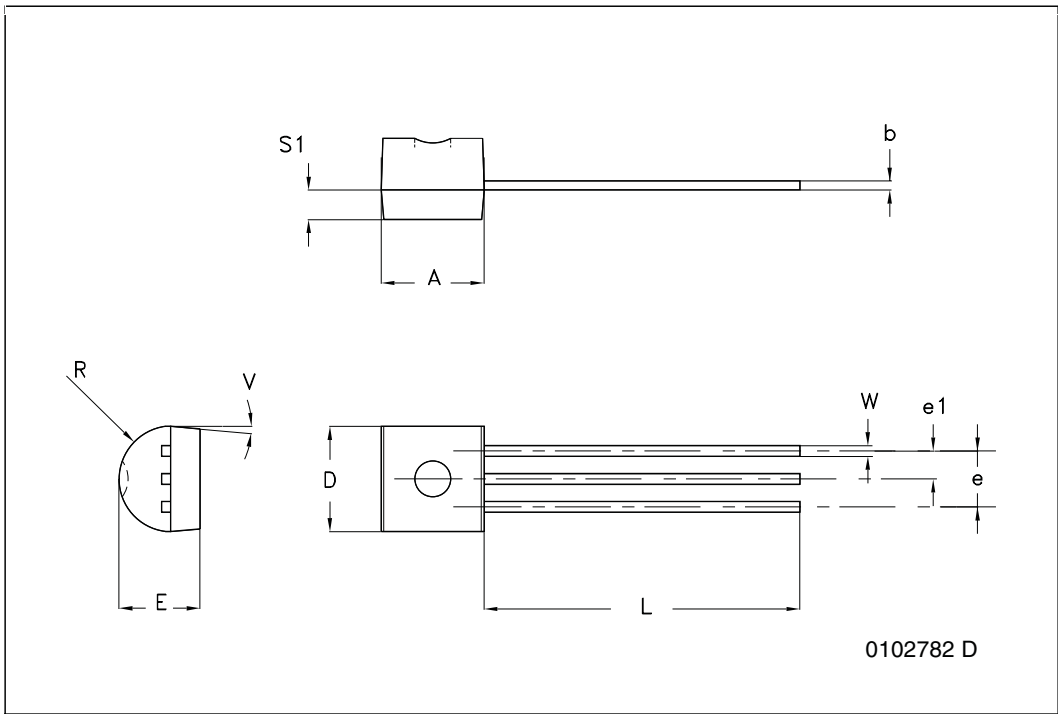
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In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

TO-92 bulk shipment mechanical data

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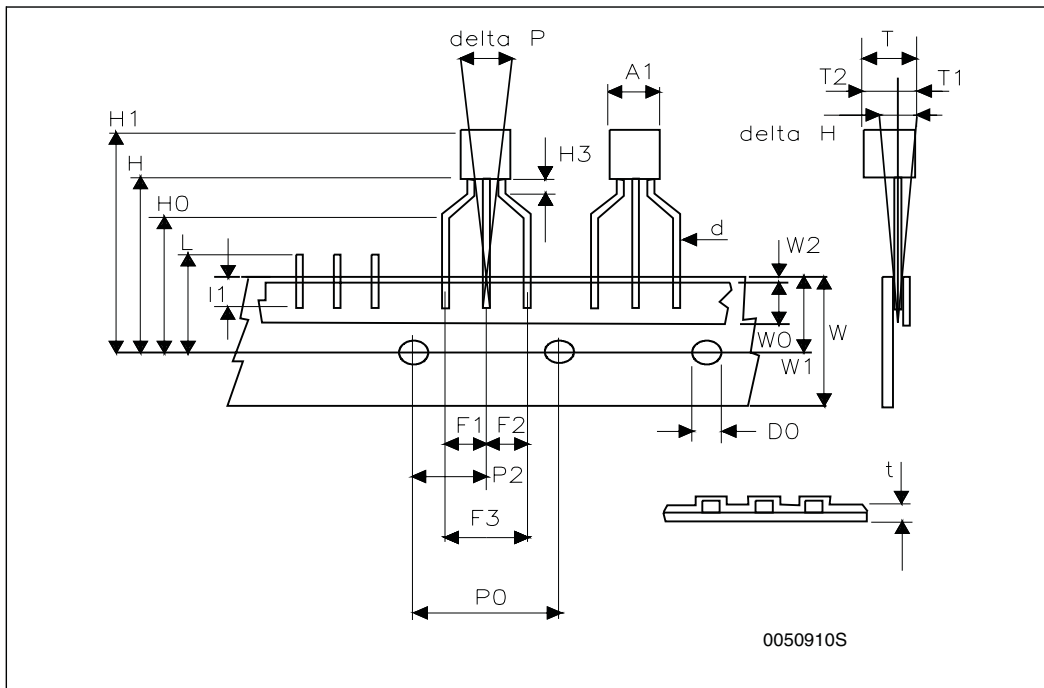
DIM.	mm.		
	MIN.	TYP	MAX.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	



TO-92 ammpack shipment (suffix"-AP") mechanical data

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Dim.	mm		
	Min	Typ	Max
A1			4.80
T			3.80
T1			1.60
T2			2.30
d			0.48
P0	12.50	12.70	12.90
P2	5.65	6.35	7.05
F1,F2	2.44	2.54	2.94
F3	4.98	5.08	5.48
delta H	-2.00		2.00
W	17.50	18.00	19.00
W0	5.70	6.00	6.30
W1	8.50	9.00	9.25
W2			0.50
H	18.50		20.50
H3	0.5	1	1.5
H0	15.50	16.00	16.50
H1			25.00
D0	3.80	4.00	4.20
t			0.90
L			11.00
I1	3.00		
delta P	-1.00		1.00



4 Revision history

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Table 5. Document revision history

Date	Revision	Changes
01-Apr-2009	1	First release.

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